

2.0 A Single-Phase Silicon Bridge Rectifier Rectifier Reverse Voltage 50 to 1000V



Features

- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Ideal for printed circuit board mounting
- High surge current capability
- High temperature soldering guaranteed 265 ℃/10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

Case: Reliable low cost construction utilizing

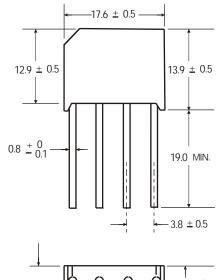
molded plastic technique

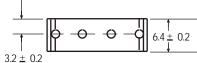
Terminals: Plated leads solderable per MIL-STD-202,

Method 208

Mounting Position: Any

Weight: 0.10 ounce, 2.53 grams (approx)





Dimensions in millimeters(1mm =0.0394")

Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz. For Capacitive load derate current by 20%.

or capacitive lead derate carrettely 2070.									
Parameter	Symbo	RS201	RS202	RS203	RS204	RS205	RS206	RS207	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=50°C	IF(AV)	2.0							Α
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							А
Rating for fusing (t<8.3ms)	l ² t	10							A ² sec
Typical thermal resistance per element (1)	ReJA	50.0							°C / V
Typical junction capacitance per element (2)	Сј	24							pF
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz. For Capacitive load derate by 20 %.

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Parameter	Symbol	RS201	RS202	RS203	RS204	RS205	RS206	RS207	Unit	
Maximum instantaneous forward voltage drop per leg at 2.0	VF	1.1						V		
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =100°C		10 500						μΑ		

Notes: (1)Thermal resistance from Junction to Ambemt on P.C.board mounting.

(2)Measured at 2.0MHz and applied reverse voltage of 4.0 volts.





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Rating and Characteristic Curves (TA=25°C Unless otherwise noted)

Fig. 1 Derating Curve for Output Rectified Current

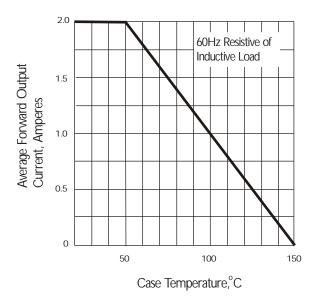


Fig. 3 Typical Instantaneous Forward Characteristics

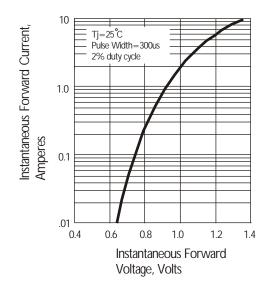


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

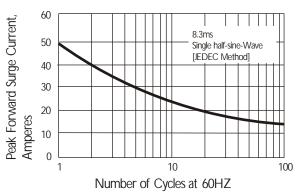


Fig. 4 Typical Reverse Characteristics

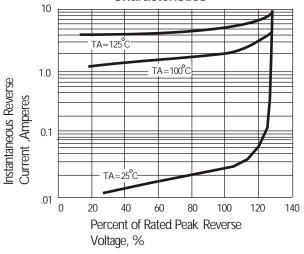


Fig. 5 Typical Junction Capacitance

